2N4137

SILICON NPN TRANSISTOR



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N4137 is a silicon epitaxial planar NPN transistor designed for ultra high speed saturated switching applications.





MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Collector-Base Voltage	V _{CBO}	40	V
Collector-Emitter Voltage	V _{CES}	40	V
Collector-Emitter Voltage	V_{CEO}	20	V
Emitter-Base Voltage	V_{EBO}	4.5	V
Continuous Collector Current	IC	200	mA
Peak Collector Current (tp=10µs)	I _{CM}	500	mA
Power Dissipation	P_{D}	360	mW
Power Dissipation (T _C =25°C)	P_{D}	1.2	W
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +200	°C
Thermal Resistance	Θ_{JA}	486	°C/W
Thermal Resistance	Θ JC	146	°C/W

ELECTRICAL	CHARACTERISTICS: (T _A =25°C un	less otherwise	noted)	
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I _{CES}	V _{CE} =20V		400	nA
I _{CBO}	V _{CB} =20V, T _A =150°C		30	μΑ
BV _{CBO}	I _C =10μA	40		V
BV _{CES}	I _C =10μA	40		V
BV CEO	I _C =10mA	20		V
BVEBO	I _E =10μA	4.5		V
V _{CE(SAT)}	I _C =10mA, I _B =1.0mA		200	mV
V _{CE(SAT)}	I _C =10mA, I _B =3.3mA		180	mV
VCE(SAT)	I _C =30mA, I _B =3.0mA		250	mV
V _{CE(SAT)}	I _C =100mA, I _B =10mA		500	mV
V _{BE} (SAT)	I _C =10mA, I _B =3.3mA	0.74	1.0	V
V _{BE} (SAT)	I _C =30mA, I _B =3.0mA		1.15	V
V _{BE(SAT)}	I _C =100mA, I _B =10mA		1.6	V
h _{FF}	V _{CF} =1.0V, I _C =10mA	40	120	
hFF	V _{CF} =0.35V, I _C =10mA	40	120	
h _{FE}	V_{CF} =0.35V, I_{C} =10mA, T_{A} =-55°C	20		
hFF	V _{CF} =0.4V, I _C =30mA	30		
hFE	V _{CE} =1.0V, I _C =100mA	20		

R0 (24-September 2018)

2N4137

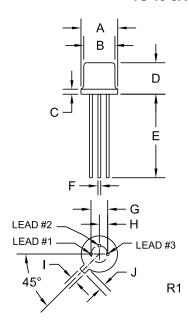
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 $\textbf{ELECTRICAL CHARACTERISTICS - Continued:} \ (T_{A} = 25 ^{\circ}\text{C unless otherwise noted})$

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
f_{T}	V_{CE} =10V, I_{C} =10mA, f=100MHz	500		MHz
C _{ob}	V_{CB} =5.0V, I_E =0, f=140kHz		4.0	pF
^t on	V_{CC} =15V, I_{C} =10mA, I_{B1} =3.3mA		12	ns
^t off	V_{CC} =15V, I_{C} =10mA, I_{B1} = I_{B2} =3.3mA		12	ns
t _s	I _C =10mA, I _{B1} =I _{B2} =10mA		13	ns

TO-18 CASE - MECHANICAL OUTLINE



DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
A (DIA)	0.209	0.230	5.31	5.84
B (DIA)	0.178	0.195	4.52	4.95
С	-	0.030	-	0.76
D	0.170	0.210	4.32	5.33
E	0.500	-	12.70	-
F (DIA)	0.016	0.019	0.41	0.48
G (DIA)	0.100		2.	54
Н	0.050		1.3	27
I	0.036	0.046	0.91	1.17
J	0.028	0.048	0.71	1.22

TO-18 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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Product End of Life Notification

PDN ID:	PDN01175
Notification Date:	4/28/21
Last Buy Date:	10/28/21
Last Shipment Date	4/28/22

Summary: The 2N4137 small signal transistor is discontinued and now classified as End Life (EOL).

Although Central Semiconductor Corp. makes every effort to continue to produce devices that have been proclaimed EOL (End of Life) by other manufacturers, it is an accepted industry practice to discontinue certain devices when customer demand falls below a minimum level of sustainability. Accordingly, the following product(s) have been transitioned to End of Life status as part of Central's ongoing Product Management Process. Any replacement products are noted below. The effective date for placing last purchase orders will be six (6) months from the date of this notice and twelve (12) months from the notice date for final shipments, and minimum order quantities may apply. The last purchase and shipment dates may be extended if inventory is available.

* All Plating types (PBFREE,TIN/LEAD) for each item listed are included in this notice.

Central Part Number	Suggested Replacement
2N4137	N/A

Central would be happy to assist you by providing additional information or technical data to help locate an alternate source if we have no replacement available. Please email your requests to engineering@centralsemi.com.

DISCLAIMER: This End of Life (EOL) notification is in accordance with JEDEC standard JESD48 - Product Discontinuance. Central Semiconductor Corp. will make every effort to offer life-time buy (LTB) opportunities and/or offer replacement devices to existing customers for discontinued devices, however, one or both may not be possible for all devices. Please contact your local Central Semiconductor sales representative for LTB opportunities/additional information.

CCC785 REV 002